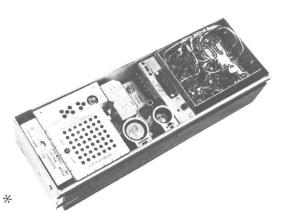


# MASTR Progress Line

406-470 MHz, 35 & 70-WATT TRANSMITTER MODELS 4ET59D30-41 & 4ET60D30-41



**SPECIFICATIONS**\*

FCC Filing Designation:

Frequency Range:

Power Output:

Crystal Multiplication Factor:

Frequency Stability:

Modulation:

Audio Frequency Characteristics

Distortion:

Tubes & Transistors:

Maximum Frequency Spacing:

Duty Cycle:

Mobile-

Station-

ET-59-D-5

406-420 & 450-470 MHz

35 watts minimum (20 watts minimum in 6-volt systems)

 $\pm 0.0005\%$  (-35°C to +60°C)

Adjustable from 0 to ±5 kHz (Narrow Band) and 0 to ±15 kHz (Wide Band) swing with instantaneous modulation limiting.

ET-60-D-5

70 watts minimum

406-420 &

450-470 MHz

Within +1 dB to -3 dB of a 6 dB/octave preemphasis from 300 to 3000 Hertz per EIA standards. Post limiter filter per FCC and EIA.

Less than 5%

Transmitter with no Options:

3 tubes

8 silicon transistors

4 diodes & 2 varactors

0.2%

20% transmit (one minute transmit, four minutes off)

Continuous

\*These specifications are intended primarily for the use of the serviceman. Refer to the appropriate Specification Sheet for the complete specifications.

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WARNING -

No one should be permitted to handle any portion of the equipment that is supplied with high voltage; or to connect any external apparatus to the units while the units are supplied with power. KEEP AWAY FROM LIVE CIRCUITS.

### **DESCRIPTION**

The MASTR Progress Line FM Transmitters Types ET-59-D and ET-60-D are crystal-controlled, phase-modulated transmitters designed for one-, two-, or four-frequency operation within the 406-420 and 450-470 megahertz bands. The transmitters consist of the following modules:

- Transistorized Exciter Board, with audio, oscillator, modulator, amplifier and multiplier stages,
- Multipliers, IPA and power amplifier stages,
- Optional transistorized Channel Guard Low-Pass filter.

All input leads to the transmitters are individually filtered by the 20-pin feed-through by-pass connector J101. The output passes through a two-section, band-pass filter, followed by a low-pass filter.

### **CIRCUIT ANALYSIS**

Eight silicon transistors and only three tubes are used in the transmitters. The frequency of the crystals used ranges from 11.25 to 11.67 and 12.5 to 13.05 megahertz, and the crystal frequency is multiplied 36 times.

A centralized metering jack (J102) is provided for use with General Electric Test Set 4EX3A10. The Test Set meters the multiplier, amplifier and PA stages as well as filament and regulated supply voltages. The metering jack also provides access to audio, microphone and push-to-talk leads.

### POWER INPUTS

The following supply voltages are connected from the power supply to the transmitter through the 20-pin by-pass connector J101:

- Pin 3 Filament voltage
- Pin 4 +300 volts MULT & IPA B+
- Pin 5 -45 volts bias
- Pin 14- +10 volts for Channel Guard option
- Pin 15- -20 volts for Exciter Board

- NOTE -

The PA B-plus voltage will vary due to the different power supplies used (both mobile and station), and due to the power input limitations of different services Refer to the PA Plate Voltage Chart on the Transmitter Schematic Diagram for the different operating conditions.

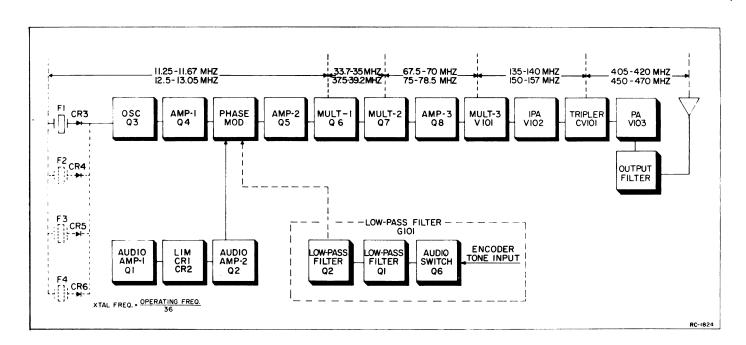


Figure 1 - Transmitter Block Diagram

#### OSCILLATOR

A transistorized Colpitts oscillator (Q3) is used in the transmitter. The oscillator crystal is thermistor-compensated at both ends of the temperature range to provide instant frequency compensation, with a frequency stability of  $\pm .0005\%$  without crystal ovens or warmers.

In single-frequency transmitters, a jumper (from H1 to H2) connects the F1 crystal keying lead to ground to forward bias diode CR3. Forward biasing the diode reduces its impedance, and the crystal frequency is applied to the base of oscillator Q3. Feedback for the oscillator is developed across C34/C35. The oscillator output is coupled through an impedance matching emitter-follower amplifier stage (Q4) to the phase modulator.

In multi-frequency transmitters, the single oscillator transistor is used, and up to three additional crystal circuits, identical to the Fl crystal circuit, can be added. The keying jumper is removed and the proper crystal frequency is selected by switching the crystal keying lead to ground by means of a frequency selector switch on the Control Unit.

### AUDIO AMPLIFIERS AND LIMITER

An audio signal from the microphone is coupled through C1 to the base of Class A audio amplifier Q1. The design of the microphone, in conjunction with C2 and R3, produces a 6-dB audio pre-emphasis. RF decoupling is provided by C75.

The amplified audio signal is RC coupled to the diode limiters CR1 and CR2 These diodes operate in series and are normally in a forward conducting state. An audio signal of sufficient amplitude to cause limiting takes the diodes out of conduction, so that one diode conducts only on positive cycles and the other conducts only on negative cycles.

Following the limiter stage is a second Class A amplifier, Q2. The output of Q2 is coupled through MOD ADJUST potentiometer R12 to a combined post-limiter filter and deemphasis network. This network consists of R15, R16, R17, C4, C7 and C8/C9. The output of the filter and deemphasis network is applied directly to the phase modulator.

### PHASE MODULATOR

The phase modulator uses varactor CV1 (voltage variable capacitor) in series with tuneable coil L1/L2. This network appears as a series-resonant circuit to the RF output of the oscillator. An audio signal applied to the modulator varies the bias of CV1, resulting in a phase-modulated output. The output of the modulator is coupled

through blocking capacitor C41/C45 to the base of the second amplifier. For Channel Guard transmitters, a second modulator stage (L3/L4 and CV2) is cascaded with the first modulator. The output of the Channel Guard encoder is fed through CHANNEL GUARD MOD ADJUST R34 to the tone modulator stage.

#### AMPLIFIERS AND 1ST AND 2ND MULTIPLIERS

The second amplifier (Q5) isolates the modulator from the loading effects of the first amplifier and provides amplification. The output is DC coupled to the first multiplier.

Following Q5 are two inductively coupled Class C, common-emitter multiplier stages (Q6 and Q7). Q6 is a tripler, with collector tank T1 tuned to three times the crystal frequency. Metering resistor R37 is for metering the MULT-1 stage at centralized metering jack J102.

Q7 operates as a doubler stage, with collector tank T3 tuned to six times the crystal frequency. Resistor R39 is for metering the MULT-2 stage at J102. The output of Q7 is inductively coupled through T3 and T4 to amplifier Q8. In 450-470 megahertz transmitters, capacitor C58 provides some high-side capacitive coupling.

Third amplifier Q8 is a neutralized straight-through amplifier. Feedback through C65 from the output link on T5 provides neutralization. This stage is metered at J102-3 across R43. The output is coupled to the grid tank of multiplier V101.

### 3RD MULTIPLIER

The output of the transistorized Exciter is coupled by a short length of RF cable to the grid tank (Z101/Z102) of beam pentode V101. This stage operates as a doubler with the plate tank tuned to twelve times the crystal frequency.

Bias voltage (approximately -18 volts) is supplied to the grid of V101 through R108 to protect the tube against loss of drive. Grid voltage is metered by metering network R105 and R106 with a residual reading of approximately 0.18 volts without any drive, caused by fixed bias voltage to the grid of V101. The plate tank is tuned by C104 with plate voltage supplied through L101.

### IPA AND TRIPLER

The output of the MULT-3 stage is coupled by a pi-network consisting of C104, L102/L103 and C107/C108 to the grid of the IPA, a compactron beam power amplifier.

Approximately 45 volts of bias voltage is supplied to the grid of V102 through R112 and a tap on L102/L103 to protect the stage

against loss of drive. A residual reading of 0.28 volt without any drive to the stage indicates the presence of fixed bias. Grid voltage and the tripler varactor bias voltage are metered simultaneously at J201-5.

The IPA plate tank is tuned by C115, and plate voltage is supplied through L105. The stage is neutralized by C110.

RF from the IPA is coupled through C118/C119 to a passive tripler stage. The tripler consists of three tuned stages (C115 & L107/L108, C121 & L110/L111, and C122 & L112/L113) which are coupled together through the common impedance of varactor CV101.

The IPA output is fed to the tripler, where the first tuned stage resonates at the fundamental frequency. The second tuned circuit (an "idler" circuit) is tuned to twice the input signal, and mixes with the input signal to produce the desired third harmonic (or operating frequency). The third tuned circuit is tuned to the operating frequency.

#### POWER AMPLIFIER

Drive from the tripler stage is link-coupled to the grid circuit of V103 through L115 and L116. V103 is a coaxial element, conduction-cooled beam power tetrode operating as a neutralized Class C amplifier.

The grid line L127/L128 of V103 is series-tuned by C130 with 20 volts of protective bias supplied through L117 and grid bias resistors R103 and R129. PA grid current is metered across resistor R103 at J102-6 and J102-14.

Neutralization is provided by a fixed series screen inductance (the fingers on the screen by-pass ring) and the screen by-pass capacitors C135, C136, C138 and C140.

The PA Plate tank circuit is comprised of C145 (the plate tank tuning flap), L119/L120 (the copper-plated heat sink on the plate of V103), and mechanically constructed capacitor (with mica dielectric) C143. The plate voltage is supplied through choke L122, which is connected to feed-through capacitor C142.

The PA screen voltage is controlled by OUTPUT CONTROL potentiometer R124 which is in series with R123/R126 in the screen supply circuit. With the OUTPUT CONTROL fully counterclockwise, the plate dissipation of V103 is reduced below the rated tube limit for tuning the power amplifier stage.

Plate current is metered from J102-1 to J102-9 across metering resistor R102 in high-power units. In medium-power units, R101 is added in series with R102.

### WARNING

The meter leads are at plate potential (high B-plus) when metering the PA Plate.

The output of V103 is link-coupled to band-pass filter FL101/FL102 consisting of two inductively coupled helical resonators. C1/C2 and C3/C4 are the output tuning capacitors. L5/L6, C5 and C6 form an additional low-pass filter section. The RF output is fed through J103 to the antenna changeover relay located on the front of the system frame.

An RF sniffer circuit (CR1, C7, and R1) provides for measuring the relative power output at J102-11. When troubleshooting the transmitter, components of the low-pass filter and RF sniffer circuit can be checked by removing the plate on the bottom of the filter casing.

#### CHANNEL GUARD

# Low Pass Filter (G101)

In encode-decode combinations, low-pass filter G101 is assembled on a printed wiring board that mounts on the underside of the MASTR transmitters. The filter is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied only when the transmitter is keyed.

Keying the transmitter applies the encoder tone (from the receiver) to low-pass filter G101. Transistors Q1 and Q2 form a two-section, active low-pass filter that reduces tone distortion and power supply ripple. Q6 operates as a tone switch, applying the tone input to the filter whenever +10 volts is applied to J1 (Q6 base). Thermistor RT1 keeps the output constant over wide variations in temperature. The filter output is coupled to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

### NOTE

When Channel Guard decode only is desired, remove the wire that connects to J6 on the low-pass filter (Encoder Tone Input).

### Encoder Model 4EH17A10 (Optional)

In encode only combinations, or when different encode and decode frequencies are required, optional encoder Model 4EH17A10

mounts on the underside of the MASTR transmitter. The encoder is supplied by a regulated +10 volts and a regulated -20 volts. The +10 volts is applied to Q3, Q4 and Q5 continuously (even in the STANDBY position). The -20 volts is applied to Q1 and Q2 only when the transmitter is keyed.

The encoder tone is provided by selective oscillators Q3 and Q4, which oscillate continuously at a frequency determined by the tone network (FL1). Negative feedback, applied through the tone network to the base of Q3, prevents any gain in the stage except at the desired encode frequency.

Thermistor-resistor combination R14 and RT2 provides temperature compensation for the oscillator output. Limiter diodes CR1 and CR2 keep the tone amplitude constant.

Keying the transmitter applied -20 volts to the two-stage, active low-pass filter (Q1 and Q2) turning them on. The oscillator output is then coupled through emitter-follower Q5 to the low-pass filter. Thermistor RT1 keeps the filter output constant over wide variations in temperatures.

The output of the filter is applied to the tone modulator on the transmitter exciter board through Channel Guard MOD ADJUST R34. Instructions for setting R34 are contained in the Modulation Adjustment section of the Transmitter Alignment Procedure.

The channel can be monitored before transmitting a message by moving the CG-OFF switch on the Control Unit to the OFF position, or by removing the microphone or handset from the operational hang-up bracket.

### **MAINTENANCE**

#### DISASSEMBLY

To service the transmitter from the top--

- Pull locking handle down and pull radio about one inch out of mounting frame.
- 2. Pry up cover at rear of transmitter.

To service the transmitter from the bottom--

- Pull locking handle down and pull radio out of mounting frame.
- Remove the two screws in bottom cover, and pry up at back of transmitter.
- 3. Slide cover back and lift off.

To remove transmitter from system frame--

- 1. Loosen the two retaining screws in the front casting (see Figure 2) and pull casting away from the system frame.
- 2. Remove the four screws in the back cover.
- 3. Remove the two screws holding the transmitter at each end of the system frame.

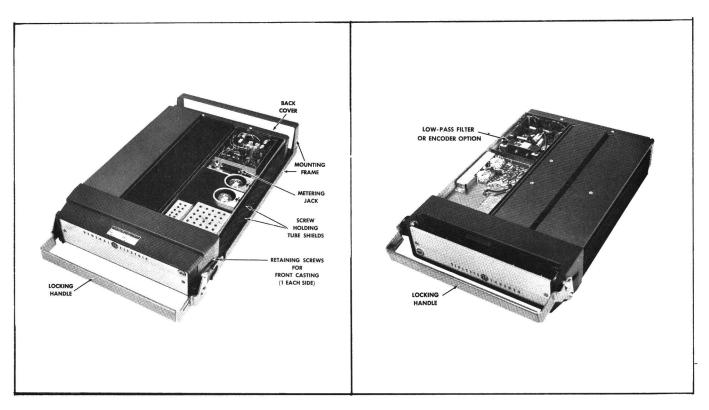


Figure 2 - Top Cover Removed

Figure 3 - Bottom Cover Removed

4. Disconnect the antenna jack in front of the transmitter and the 20-pin feedthru connector at the back of the transmitter, and slide the unit out of the system frame.

### TUBE REPLACEMENT

WARNING —

Before replacing tubes, remove all power from the unit so that the transmitter cannot be keyed. In mobile units, disconnect power plug P504. In stations, turn off the main line switch and discharge filter capacitors.

# To replace 3rd Multiplier and IPA Tubes (V101 & V102)

Loosen the two screws holding tube shield to heatsink, and pull off tube shield. Then carefully work the tube out of its socket.

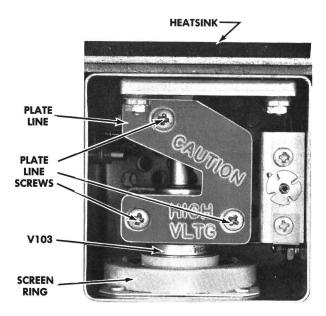


Figure 4 - PA Plate Box With Cover Removed

To replace Power Amplifier V103:

- Make sure that all power is removed from the unit.
- 2. Remove the top cover on the AMPL PLATE box (fig. 4). Allow the transmitter to cool if necessary.
- 3. Remove the three Phillips-head screws in the plate line, starting with the two screws nearest tube socket. Lift off the top section of the plate line. Next, slide the bottom section toward the AMPL PLATE tuning adjustment and lift it out of the AMPL PLATE box.
- 4. Carefully work the tube out of its socket.
- 5. Use a screwdriver to bend the screen ring contacts out toward the center of the tube socket so that all contacts will touch the base of the tube.

#### CAUTION \_

Extreme care should be taken during PA tube replacement to avoid damaging the screen ring contacts.

- 6. Replace the tube by hand, making sure that it is fully seated in the socket and that all screen ring contacts are touching the tube.
- 7. Replace the plate lines, tightening the screw nearest the heatsink first. Then replace the top cover of AMPL PLATE box.
- 8. Realign the transmitter.

### MODULATION LEVEL ADJUSTMENT

The MOD ADJUST (R12) was adjusted to the proper setting before shipment and should not normally require readjustment. This setting permits approximately 75% modulation for the average voice level. The audio peaks which would cause overmodulation are clipped by the modulation limiter. The limiter, in conjunction with the de-emphasis network, instantaneously limits the slope of the audio wave to the modulator, thereby preventing overmodulation while preserving intelligibility.

### TEST EQUIPMENT

- 1. An audio oscillator
- 2. A frequency modulation monitor
- 3. An output meter or a VTVM
- 4. GE Test Set Model 4EX3A10

### PROCEDURE

- Connect the audio oscillator and the meter across audio input terminals J5 (Green-Hi) and J6 (Black-Lo) on GE Test Set or across J1 (Mike High) and J2 (Mike Low) on the Exciter Board.
- 2. Apply a 0.75-volt signal at 1000 Hz to Test Set or across Jl and J2 on Exciter Board.
- 3. For transmitters without Channel Guard, set the MOD ADJUST (R12) for a 13 kilohertz swing with the deviation polarity which gives the highest reading as indicated on the frequency modulation monitor.
- 4. For transmitters with Channel Guard, set the Channel Guard MOD ADJUST (R34) for 1.5 kHz tone deviation. Then repeak L1/L2 and L3/L4 as shown in Step 1 of Transmitter Alignment Procedure. Reset tone deviation to 1.5 kHz deviation. Remove the tone to the transmitter by unplugging leads to J7 and J8 on Exciter Board, or by switching to a non-Channel Guard frequency in multifrequency units. Next, apply a 1.0 volt signal at 1000 Hz and set MOD ADJUST (R12) for 11.5 kHz deviation (13 kHz minus 1.5 kHz tone deviation).
- 5. For multifrequency transmitters, set the deviation as described in Steps 3 or 4 on the channel producing the largest amount of deviation.

# PA POWER INPUT

For FCC purposes, the PA power input can be determined by measuring the PA Plate voltage and the plate current indication, and using the following formula:

ET-59-D: 
$$P_i = \frac{\text{Plate Voltage x Plate Current Indication}}{3.5}$$
ET-60-D:  $P_i = \frac{\text{Plate Voltage x Plate Current Indication}}{3.5}$ 

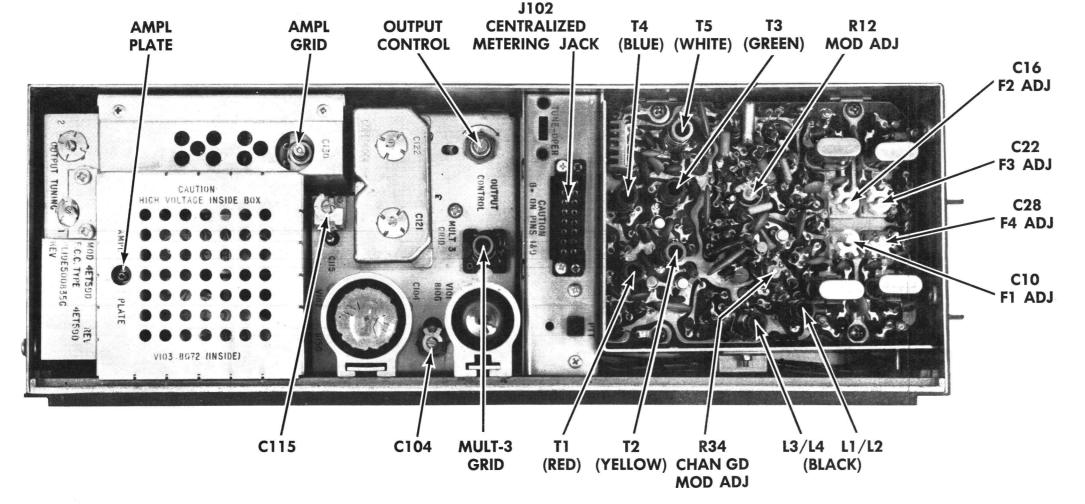
#### Whone

Pi is the power input in watts.

Plate voltage is measured with GE Test Set in position G, using the 1000-volt scale (or measured from J102-1 to -16 with multimeter).

Plate current indication is measured with GE Test Set in Position G, using the TEST 1 scale (or measured from J102-1 to -9 with multimeter).

3.5 or 2.59 is the value of the plate current metering resistor in ohms.



# TRANSMITTER ALIGNMENT

### EQUIPMENT REQUIRED

General Electric Test Set Models 4EX3A10 (TM11 or TM12), 4EX8K11, Station Test Meter Panel, or a 20,000 ohms-per-volt Multimeter with a 1-volt scale.

#### PRELIMINARY CHECKS AND ADJUSTMENTS

- 1. Place crystal (operating frequency ÷ 36) in crystal socket XY1.
- 2. For a badly mis-aligned transmitter or a large change in frequency, set crystal trimmer C10 to mid-capacity. If multi-frequency transmitter, set all trimmers to mid-capacity and tune transmitter on channel with the lowest frequency (except for Steps 15 and 16).
- 3. Turn OUTPUT CONTROL (R124) fully counterclockwise. This limits PA dissipation during initial tune-up.
- 4. Connect Test Set Model 4EX3AlO to the Transmitter Centralized Metering Jack J102. If using Multimeter, connect the positive lead to J102-16 (Ground), except where indicated.
- 5. For a large change in frequency or a badly misaligned transmitter, set the slugs in the Exciter coils at the bottom of the coil form, and the slug of ZlO1/ZlO2 (MULT-3 GRID) at the top of the coil form. Tune AMPL PLATE counterclockwise until the stud is even with the top of the case. Then turn Cl21, Cl22 and OUTPUT TUNING -1 and -2 fully counterclockwise.
- 6. All adjustments are made with the transmitter keyed.

### ALIGNMENT PROCEDURE

		POSITION Multimeter		TYPICAL METER	PROCEDURE
STEP	4EX3A10	- at J102	TUNING CONTROL	READING	
				EXCITE	
1.	A (MULT-1)	Pin 10	L1/L2 (and L3/L4 with Channel Guard)	0.8 v (0.5 v Minimum)	Tuning the modulator is a critical adjustment. Carefully tune $\mathrm{Ll}/\mathrm{L2}$ for maximum meter reading. For transmitters with Channel Guard, alternately tune $\mathrm{Ll}/\mathrm{L2}$ and $\mathrm{L3}/\mathrm{L4}$ for maximum meter reading.
2.	A (MULT-1)	Pin 10	Tl	See Pro- cedure	Tune Tl for a small dip in meter reading (not required unless changing frequency).
3.	B (MULT-2)	Pin 2	T2, T1 and T3	0.65 v (0.5 v Minimum)	Tune T2 and then T1 for maximum meter reading. Then tune T3 for minimum meter reading (not required unless changing frequency).
4.	C (AMPL-3)	Pin 3	T4, T3 and T5	0.60 v (0.5 v Minimum)	Tune T4 and then T3 for a maximum meter reading. Then tune T5 for minimum meter reading (not required unless changing frequency).
			N	MULT-3, IPA	AND POWER AMPLIFIER
5.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102)	0.6 v (0.5 v Minimum)	Tune MULT-3 GRID for maximum meter reading.
6.	C (AMPL-3)	Pin 3	Т4	Maximum	Retune T4 for maximum meter reading.
7.	D (MULT-3)	Pin 4	MULT-3 GRID (Z101/Z102)	Maximum	Retune MULT-3 Grid for maximum meter reading.
8.	E (MULT-4)	Pin 5	IPA GRID (C104) & C115	Maximum	Tune IPA GRID for maximum meter reading. Then tune Cl15 for maximum meter reading (not required unless changing frequency).
9.	E (MULT-4)	Pin 5	C121 & C122	See Pro- cedure	Tune C121 clockwise until meter reading drops abruptly. Then turn C122 clockwise for a change in meter reading. This step is not required unless changing frequency.
10.	F PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130) & C115, C121 & C122	See Pro- cedure	Tune AMPL GRID for maximum meter reading. Then retune C115, C121, C122 and AMPL GRID in that order until no further increase in meter reading is noted.
11.	G PA PLATE	WARN High B+ on Pin 1 (+) Pin 9 (-)		Minimum	Tune AMPL PLATE for a dip in meter reading (not required unless changing frequency).
12.	H REL PWR OUT	Pin 11	OUTPUT TUNING -1 & -2 and AMPL PLATE	Maximum	Alternately tune OUTPUT TUNING -1 and -2 and AMPL PLATE in that order for maximum meter reading.
13.	G PA PLATE	Pin 1 (+) Pin 9 (-)	OUTPUT CONTROL (R124)	See Pro- cedure (See note 1)	Adjust OUTPUT CONTROL for a meter reading of 0.7 volt (0.6 volt for continuous duty stations).
14.					Repeat Steps 12, 13 and 10 in that order

STEP	METERIN 4EX3A10	G POSITION Multimeter - at J102	TUNING CONTROL	TYPICAL METER READING	PROCEDURE
			FOR 1	MULTI-FREQU	ENCY UNITS ONLY
15.	F PA GRID	Pin 14 (+) Pin 6 (-)	AMPL GRID (C130)	See Pro- cedure	After completing Steps 1 thru 14 using the lowest channel frequency, alternately switch from the highest to the lowest frequency and tune AMPL GRID for equal meter readings.
16.	H REL PWR OUT	Pin 11	OUTPUT TUNING-1 and AMPL PLATE	See Pro- cedure	Alternately switch from the highest to the lowest frequency and tune OUTPUT TUNING-1 and AMPE PLATE for equal meter readings.
	•	•		FREQUENCY	ADJUSTMENT
17.					With no modulation, adjust crystal trimmers C10, C16, C22 or C28 as required. Next, refer to the MODULATION

ADJUSTMENT.

### REDUCED POWER OPERATION

- NOTE 1 In some services, FCC regulations do not permit the use of full rated power input to the PA Plate circuit. In such cases:
  - In station applications, make sure that the power transformer taps are set for the PA Plate voltage shown in the Maintenance Manual for Power Supply Type EP-38-A.
  - In mobile applications, make sure that the transformer taps are set as shown in the Maintenance Manual for the 4EP37A10, 4EP37B10, 4EP37C10 or 4EP37D10.
  - Adjust the OUTPUT CONTROL for the meter reading shown in the following chart.

	XMTR	MEASURED	METER
	TYPE	PLATE VOLTAGE	READING
For 60-Watt Input	ET-59-D	275 to 305 VDC (see Note 2)	0.7 VDC
For 120-Watt	ET-60-D	460 to 510 VDC	0.7 VDC
Input		(see Note 3)	MAX.

NOTE 2 - If the plate voltage is not within the 275 to 305-volt limit, find the OUTPUT CONTROL setting by dividing 210 by the measured plate voltage.

Meter reading in volts =  $\frac{210}{\text{Measured Plate Voltage}}$ 

NOTE 3 - If the Plate Voltage is not within the 460 to 510-volt limit, find the OUTPUT CONTROL setting by dividing 311 by the measured plate voltage.

Meter reading in volts =  $\frac{311}{\text{Measured Plate Voltage}}$ 

# ALIGNMENT PROCEDURE

LBI-3998

406-470 MHz, 35 & 60-WATT MASTR TRANSMITTER MODELS 4ET59D30-41 & MODELS 4ET60D30-41

Issue 3

LBI-3998

# **TEST PROCEDURES**

These Test Procedures are designed to as- 1, the defect can be quickly localized. Once sist you in servicing a transmitter that is oper- a defect is pin-pointed, refer to the "Service Check" and the additional corrective measures ating--but not properly. Problems encountered could be low power output, low B plus, tone and included in the Transmitter Troubleshooting voice deviation, defective audio sensitivity and Procedure. Before starting with the Transmitmodulator adjust control set too high. By follow- ter Test Procedures, be sure the transmitter is ing the sequence of test steps starting with Step tuned and aligned to the proper operating frequency.

### TEST EQUIPMENT REQUIRED

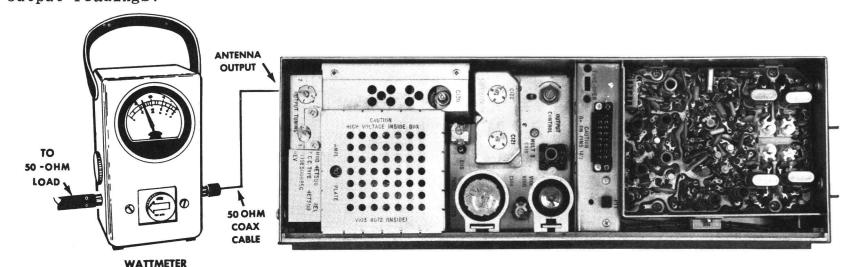
for test hookup as shown:

- 1. Wattmeter similar to: 2. VTVM similar to: Bird #43 Triplett #850
- 3. Audio Generator similar to: 4. Deviation Meter GE Model 4EX6A10 or Heath #1G-72
  - similar to: Measurements #140
- 5. Multimeter similar to: GE METERING TEST SET MODEL 4EX3A10, 4EX8K11, Triplett #631 or 20,000 ohms-per-volt voltmeter

# STEP 1

# **POWER MEASUREMENT** TEST PROCEDURE

1. Connect transmitter output to wattmeter as shown below, using a low-loss coaxial cable between the antenna jack and wattmeter. RG-303/U is recommended for accurate power output readings.



2. Key transmitter and check wattmeter for minimum reading as shown in power output chart on Transmitter Schematic Diagram.

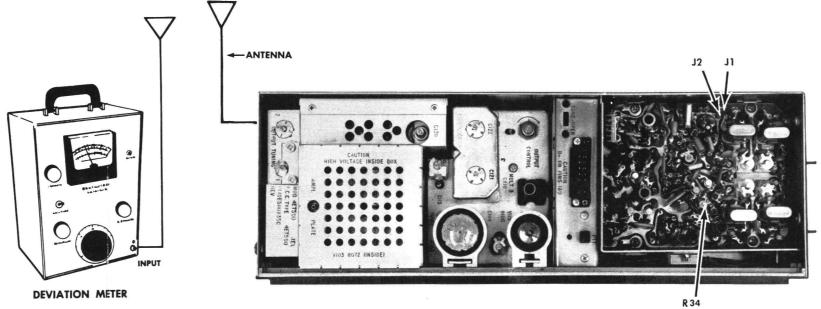
### SERVICE CHECK

Refer to Service Hints on Transmitter Troubleshooting Procedure.

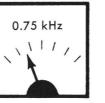
# STEP 2

# TONE DEVIATION WITH CHANNEL GUARD TEST PROCEDURE

1. Setup Deviation Meter and monitor output of transmitter as shown below:



- 2. Unplug the MIC HI terminal from Jl on Transmitter Exciter Board.
- 3. Key transmitter and check for 0.75 kHz deviation (1.5 kHz wide-band). If reading is low or high, adjust Channel Guard MOD ADJUST (R34) for a reading of 0.75 kHz.



**DEVIATION METER** 

# NOTES:

The Channel Guard MOD ADJUST (R34) may be adjusted for deviations up to 2.4 kHz for tone frequencies from 71.9 Hz to 82.5 Hz, and deviations up to 3.0 kHz for all tone frequencies above 82.5 Hz.

- 1. On units supplied with Channel Guard, the Phase Modulator Tuning should be peaked carefully to insure proper performance. (Refer to Steps 1 and 2 in the Transmitter Alignment Chart).
- 2. The Tone Deviation Test Procedures should be repeated everytime the Tone Frequency is changed.

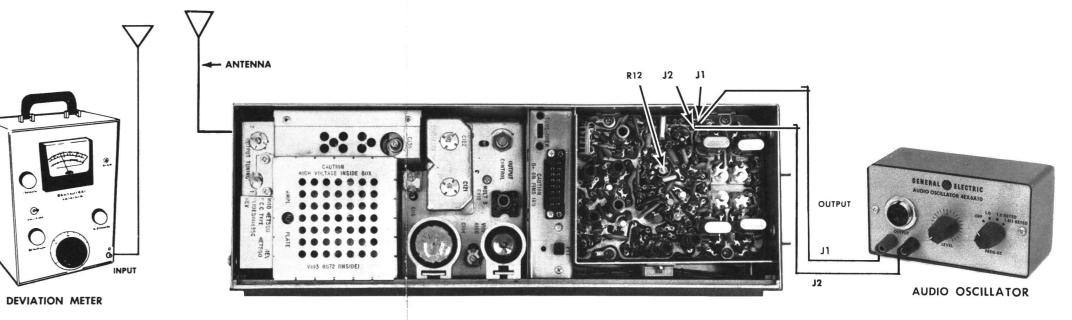
### SERVICE CHECK

If the 0.75 kHz (1.5 kHz wide-band) deviation is not obtainable when adjusting R34, replace the encoder tone network.

# STEP 3

# **VOICE DEVIATION AND SYMMETRY TEST PROCEDURE**

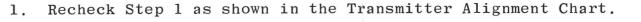
- 1. Unplug the High and Low Mike leads from the Exciter Board Jacks Jl and J2.
- 2. Connect test equipment to transmitter as shown below:

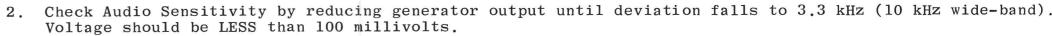


- 3. Set the generator output to 0.75 VOLTS RMS and frequency to 1 kHz.
- 4. Key the transmitter and adjust Deviation Meter to carrier frequency.
- Deviation reading should be ±4.5 kHz (±13 kHz wide-band).
- Adjust "Modulation Adjust Control" R12 until deviation reads 4.5 kHz (13 kHz wide-band) on plus (+) or minus (-) deviation, whichever is greater. This adjustment should be made with the correct level of tone applied on Channel Guard transmitters.

NOTES: --MASTR transmitters are adjusted for 4.5 kHz (13 kHz wide-band) deviation at the factory. The factory adjustment will prevent the transmitter from deviating more than 5 kHz (15 kHz wide-band) under the worst conditions of frequency, voltage and temperature.

If the deviation reading plus (+) and minus (-) differs by more than 0.5 kHz (1.5 kHz wide-band), check the following:





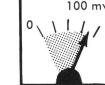


**METER** 



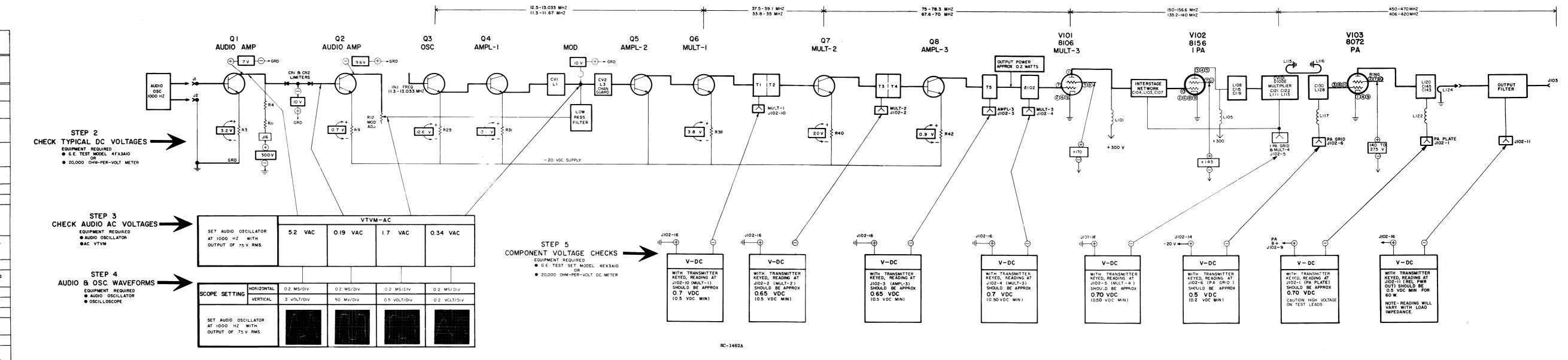






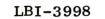
# STEP I - QUICK CHECKS

POWER_		CHE		GES AT C	er = pin	numbers						
OUTPUT			G	E Test S	et = A-G	positio	ns	PROBABLE DEFECT				
	Pins 10 & 16 A	Pins 2 & 16 B	Pins 3 & 16 C	Pins 4 & 16 D	Pins 5 & 16 E	Pins 6 & 14 F	Pins 1 & 9 G					
0	0	0	0	0.18 v	0.28 v	0	Low	Defective Q3-Q6 or Modulator (see Note A)				
0	over 1.0 v	0	0	0.18 v	0.28 v	0	Low	Shorted Q5 or open Q6				
0	0.70 v	0 or over 1.0 v	0	0.18 v	0.28 v	0	Low	Defective Q7				
0	0.70 v	0.65 v	0 or over 1.0 v	0.18 v	0.28 v	0	Low	Defective Q8				
0	0.70 v	0.65 v	low	0.18 v	0.28 v	0	Low	Open filament on 8106, open coax				
0	0.70 v	0.65 v	0.7 v	0.75 v	0.28 v	0	Low	Open filament on 8156				
0	0.70 v	0.65 v	0.7 v	0.75 v	0.75 v	0	0	Open filament on 8072				
0	0.70 v	0.65 v	0.7 v	0.75 v	0.5 v	0	0	If no peak at position "E" when tuning C115, bad multiplier diode or 8156				
0	0.72 v	0.65 v	0.7 v	0.75 v	0.75 v	high	Very Low or O	Bad R123/R126, bad R124, shorted 8072 screen				
Low	0.72 v	0.65 v	0.7 v	0.75 v	0.75 v	Low	0.70 v	Weak 8156 or 8072				
Erratic	0.72 v			0.75 v	0.75 v	Very high	0.70 v	Check contacts on screen bypass ring				
NOTE A -	Loca	lize tro	uble by	checking	:							
1.	-20	volt DC	supply a	t J102-1	2-16.							
2.	Meas	ure 12.1	VDC acr	oss Q4 e	mitter r	esistor	R31 (150	00 ohms), then:				
(a)				light va properly		in R31 v	oltage r	reading indicates Q3 and				
(b)	If n	o voltag	e is mea	sured, c	heck key	ing lead	is CR3-CF	R6, Q3, Q4.				
(c)	With volt	crystal indicat	removed es <b>Q</b> 5 ar	l, short nd Q6 are	Q5 base operati	to emiti	ter. A verly. De	voltage reading above 1.0 efect may be in Modulator.				
(d)	If m	odulator	is defe	ctive. c	heck vol	tage vai	riable di	lodes CV1 and CV2.				

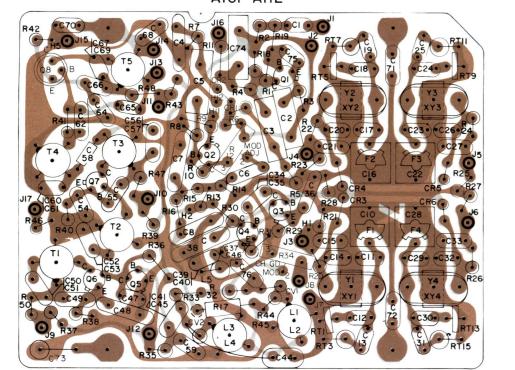


# TROUBLESHOOTING PROCEDURE

406-470 MHz, 35 & 60-WATT TRANSMITTER MODELS 4ET59D30-41 & 4ET60D30-41



**EXCITER** A101 - A112



RANSISTOR	E1.	TTER	84	ISE .	COLL	ECTOR
	-	+	-	+	-	+
Qτ	6.5×	6.8	240k	12k	50 K	20k
<b>0</b> 2	6 2k	44	70k	ION	9 8	10+
<b>Q</b> 3	9k	2 7k	9k	2 24	100	100
Ôr†	7×	5×	9⊮	2 7k	100	100
Q5	5×	2.74	70k	6.8+	3 74	2 31
06	48	3 2h	3 7k	2.3k	175	. 75
Q7	5 2K	2 9+	5K	2 7k	465	465
08	5k	2 74	5×	2 7k	5."	6.

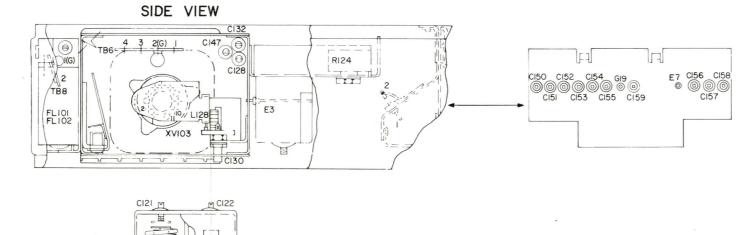
STOR	EMI	*166	BAS	SE .	301.	E. TOF
	-	+	-	+	-	+
	1.1k	144	240k	30×	60i	35 H
	1k	19	70K	4 3F	144	181
	2 6+	2 50	104	· 5+	2 %	5 1
	5⊭	5⊭	2.6*	2.5⊭	2 %	5 11
	C	- C	70k	≥ 2k	8.2+	3 8
)	340	360	8h	3 8⊁	3k	5 1
	6C	180	C	0	2 3k	5 5
l	27	27	47	47	2.6×	5,

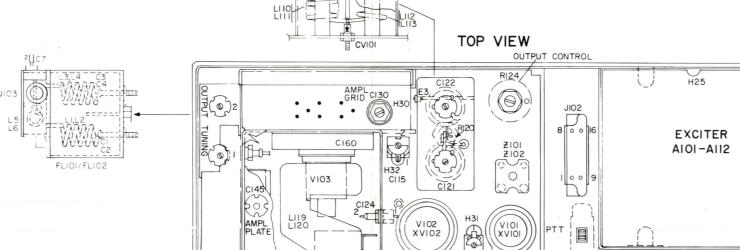
SISTOR	Ewi	*1Eb	BAS	SE.	301.	E. "OF
	-	+	-	+	-	+
QΙ	k	144	240k	30k	60F	35 H
Ø5	1k	18	70K	4 3F	144	181
Q3	2.6	2 50	104	· 5+	2 %	5 1
Ç.	5*	5+	2.6*	2.5⊭	2 %	5 11
Q5	C	ı Ç	20k	⇒ 2k	8.2	3 8
Q6	346	360	8h	3 8⊧	3k	5 1
Q7	60	180	C	0	2 3k	5 5
08	27	27	47	47	2.6⊭	5+

RUNS ON SOLDER SIDE

RUNS ON COMPONENT SIDE

- RUNS ON BOTH SIDES



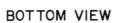


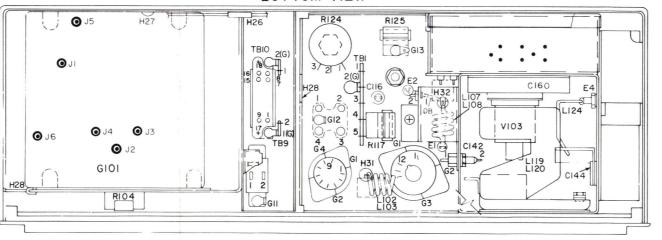


\* IST READING FOR SINGLE FREQ. 2ND READING FOR MULTI-FREQ.

# RESISTANCE READINGS

FOR READINGS OF: USE SCALE:  $\begin{array}{c} \text{I-IOO}\,\Omega\\ \text{IOO-IK}\,\Omega\\ \text{IK-50K}\,\Omega\\ \text{50K-}\infty\,\Omega \end{array}$ X I X IO X I,000 X I00,000





N	1	2	3	4	5	6	7	8	9	10	LT.	12
01	20 K	0	46 K	1Ω	0	0	32K	46 K	0		1	
02	ıΩ	0	19 K	19 K	19K	0	24K	0	0	55K	24 K	0
03	0	~	2K/6K *	0	0	ιΩ	12.5 K	2K/6K*	0		2K/6K*	

\* READING DEPENDS ON METER POLARITY.

LOW-PASS FILTER

# **OUTLINE DIAGRAM**

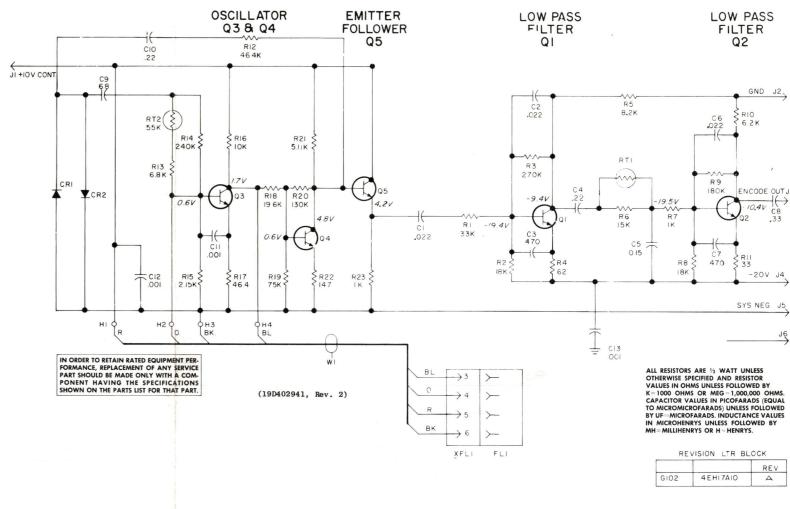
406-470 MHz, 35 & 60-WATT TRANSMITTER MODELS 4ET59D30-41 & 4ET60D30-41

Issue 5

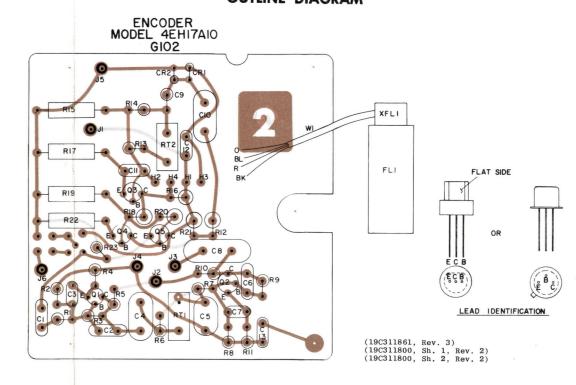
# (19R621286, Rev. 6)

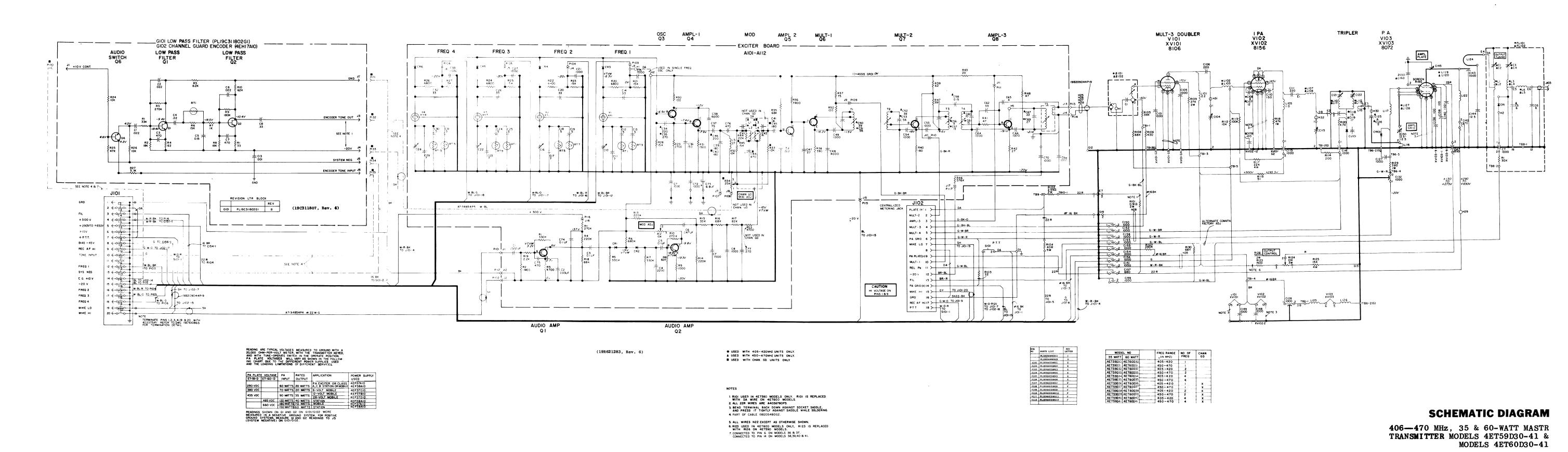
# CHANNEL GUARD ENCODER MODEL 4EH17A10

# SCHEMATIC DIAGRAM



# **OUTLINE DIAGRAM**





# PARTS LIST LBI-4025E 405-470 MHz TRANSMITTER MODELS 4ET59D30-35 STANDARD

hru A101 19D402308G1 4ET59D30, 4ET60D30 1 Freq	SYMBOL	GE PART NO.	DESCRIPTION
19A116080P3   Polyester: 0.022 μf ±20%, 50 VDCW.	AlOl thru All2		A101 19D402308C1 4ET59D30, 4ET60D30 1 Freq A102 19D402308C3 4ET59D31, 4ET60D31 1 Freq A103 19D402308C3 4ET59D32, 4ET60D32 2 Freq A104 19D402308C3 4ET59D33, 4ET60D33 2 Freq A105 19D402308C5 4ET59D33, 4ET60D34 4 Freq A107 19D402308C6 4ET59D35, 4ET60D35 1 Freq A108 19D402308C6 4ET59D37, 4ET60D35 1 Freq A109 19D402308C9 4ET59D35, 4ET60D38 2 Freq A110 19D402308C1 4ET59D39, 4ET60D38 2 Freq A111 19D402308C10 4ET59D39, 4ET60D39 2 Freq A111 19D402308C11 4ET59D40, 4ET60D40 4 Freq
19a116080P4   Polyester: .033 μf ±20%, 50 VDCW.			
C3 194116080P7 Polyester: 0.1 µf ±20%, 50 VDCW. C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL. C5 19416080P5 Polyester: 0.1 µf ±20%, 50 VDCW. C6 19416080P5 Polyester: .047 µf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20. C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C12 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C19 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C22 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C23 5496219P7 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C25 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C26 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C27 5494481P11 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C29 5496219P751 Ceramic disc: 30 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C29 5496219P7 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			· ·
C4 7491395P114 Ceramic disc: 2200 pf ±10%, 500 VDCW; sim to RMC Type JL.  C5 19A16080P7 Polyester: 0.1 µf ±20%, 50 VDCW.  C6 19A16080P5 Polyester: 0.47 µf ±20%, 50 VDCW.  C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL.  C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C23 5496219P7 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C24 and c25 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C26 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 549481P11 Ceramic disc: 30 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P751 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C29 5496219P7 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			
to BMC Type JL.  C5 19A116080P7 Polyester: 0.1 µf ±20%, 50 VDCW.  C6 19A116080P5 Polyester: 0.47 µf ±20%, 50 VDCW.  C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to BMC Type JL.  C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5496219P751 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C23 5496219P7 Ceramic disc: 3pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 3pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 3pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C28 5496219P751 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C28 5496219P70 Ceramic disc: 1000 pf ±0%, 1000 VDCW; sim to RMC Type JF Discap.  C29 5496219P70 Ceramic disc: 7pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P70 Ceramic disc: 7pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P70 Ceramic disc: 5pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 5pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 5pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			Ceramic disc: 2200 pf ±10%, 500 VDCW; sim
C6 19A116080P5 Polyester: .047 μf ±20%, 50 VDCW. C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL. C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20. C10 549127lP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C12 and c13 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C16 549127lP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C18 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C18 29 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C20 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM. C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C23 5496219P7 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap. C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C25 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C26 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM. C27 5494481P111 Ceramic disc: 33 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189. C28 5496219P7 Ceramic disc: 33 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 33 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM. C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			to RMC Type JL.
C7 7491395P111 Ceramic disc: 1500 pf ±10%, 500 VDCW; sim to RMC Type JL.  C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 549127lP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 and coef 0 PPM.  C13 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 549127lP106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 and coef 0 PPM.  C18 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P7 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 5496219P70 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 5496219P71 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 5496219P70 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P70 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 5 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			
to BMC Type JL.  C8 5493367P1000K Silver mica: 1000 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-20.  C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 and c13 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C15 5496219P751 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 and c19 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C23 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C24 19C300685P93 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C25 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C22 5496219P751 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C28 5496219P751 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	•-	i	1
C10 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C11 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C12 and C13 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C14 5496219P751 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C21 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C28 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C29 5496219P76 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C28 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.			to RMC Type JL.  Silver mica: 1000 pf ±10%, 100 VDCW; sim to
Coef 0 PPM.   Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C10	5491271P106	Variable: approx 2.1 to 12.7 pf, 750 v peak;
Coef 0 PPM.   Coef 0 PPM.	C11	5496219P7	
-750 PPM.  C15 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C16 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C21 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	and	19C300685P93	
RMC Type JF Discap.  Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C17 5496219P7	C14	5496219P751	
C17 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C18 and c19  Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C21 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C25 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.  C26 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C27 5494481P111 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C15	5494481P111	RMC Type JF Discap.
Coef 0 PPM.   Coef 0 PPM.	C16	5491271P106	Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.
coef 0 PPM.  C20 5496219P751 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C21 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 and c25 C26 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef oppm.  C29 5496219P7 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef oppm.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C30 20 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C17	5496219P7	coef 0 PPM.
-750 PPM.  C21 5494481P111 Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 and c25 C26 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	and	19C300685P93	
RMC Type JF Discap.  C22 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189.  C23 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C24 and c25  C26 5496219P751 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.  C27 5494481P111 Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C20	5496219P751	
Sim to EF Johnson 189.   Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.   Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.   Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.   Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.   Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.   Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.   Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.   Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.   Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp	C21	5494481P111	RMC Type JF Discap.
Coef 0 PPM.   Coef 0 PPM.	C22	5491271P106	sim to EF Johnson 189.
coef 0 PPM.	C23	5496219P7	coef 0 PPM.
-750 PPM.  C27 5494481P111 Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.  C28 5491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 5496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	and	19C300685P93	
C28 S491271P106 Variable: approx 2.1 to 12.7 pf, 750 v peak; sim to EF Johnson 189-6-5.  C29 S496219P7 Ceramic disc: 7 pf ±0.5 pf, 500 VDCW, temp coef 0 PPM.  C30 and 19C300685P93 Ceramic disc: 5 pf ±0.1 pf, 500 VDCW, temp coef 0 PPM.	C26	5496219P751	-750 PPM.
sim to EF Johnson 189-6-5.  C29 5496219P7	C27	5494481P111	RMC Type JF Discap.
Coef 0 PPM.	C28	5491271P106	sim to EF Johnson 189-6-5.
and coef 0 PPM.	C29	5496219P7	coef 0 PPM.
	and	19C300685P93	

SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
C32	5496219P751	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef -750 PPM.	C73	5496267P18
C33	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	C74	19A115414P13
C34	5496372P50	Ceramic disc: 220 pf ±5%, 500 VDCW, temp coef	C75	5494481P107
C35	5496372P54	-2200 PPM.  Ceramic disc: 270 pf ±5%, 500 VDCW, temp coef	C76	5493366P470K
C36	5496219P467	-2200 PPM.  Ceramic disc: 150 pf ±5%, 500 VDCW, temp coef	C77	5493366P270K
•	·	-220 PPM.  Ceramic disc: 75 pf ±10%, 500 VDCW, temp coef		
C37	5496372P327	-4700 PPM.	CR1	19A115250P1
C38	5494481P131	Ceramic disc: 6800 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	and CR2	
C39	5496372P145	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -3300 PPM.	CR3 thru	19A115603P1
C40	5496372P345	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -4700 PPM.	CR6 CV1	5495769P8
C41	5493366P180K	Silver mica: 180 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	and CV2	
C44	5493366P470J	Silver mica: 470 pf ±5%, 100 VDCW; sim to Electro Motive Type DM-15.	J1	4033513P4
C45	5496372P45	Ceramic disc: 180 pf ±10%, 500 VDCW, temp coef -2200 PPM.	thru J17	
C46	5496372P347	Ceramic disc: 200 pf ±10%, 500 VDCW, temp coef	L1	19B204526G2
C47	5496219P749	Ceramic disc: 27 pf ±5%, 500 VDCW, temp coef	L2	19B204526G1
C48	5494481P129	Ceramic disc: 3900 pf ±20%, 1000 VDCW; sim to	L3 R1	19B204526G4 3R152P333J
C49	5494481P111	RMC Type JF Discap.  Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to	L4 R1	19B204526G3 3R152P333J
		RMC Type JF Discap.	L5	7488079P48
C50	5496219P253	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.		
C51	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q1	19A115123P1
C52	5496219P253	Ceramic disc: 39 pf ±5%, 500 VDCW, temp coef -80 PPM.	and Q2	19811312371
C53	5496219P257	Ceramic disc: 56 pf ±5%, 500 VDCW, temp coef -80 PPM.	Q3 thru	19A115330P1
C54 and C55	5494481P111	Ceramic disc: 1000 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	Q5 Q6 and Q7	19A115328P1
C56	5496219P440	Ceramic disc: 9 pf ±0.25 pf, 500 VDCW, temp	Q8	19A115329P2
C57	5496219P343	Ceramic disc: 13 pf ±5%, 500 VDCW, temp coef -150 PPM.		
C58	5491601P35	Phenolic: 0.15 pf ±10%, 500 VDCW.	Rl	3R77P334K
C59	5493366P220K	Silver mica: 220 pf $\pm 10\%$ , 100 VDCW; sim to Electro Motive Type DM-15.	R2	3R77P105K
C60	5496219P241	Ceramic disc: 10 pf ±0.25 pf 500 VDCW, temp coef	R3 R4	3R77P472K 3R77P224K
C61	5496219P244	-80 PPM.  Ceramic disc: 15 pf ±5%, 500 VDCW, temp coef	R5	3R77P334K
201		-80 PPM.	R6	3R77P684K
C62	19A116656P33J0	Ceramic disc: 33 pf ±5%, 500 VDCW, temp coef 0 PPM.	R7	3R77P334K
C64	5494481P111	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.	R8	3R77P823K
C65	5496219P35	Ceramic disc: 4 pf ±0.25 pf, 500 VDCW, temp coef	R9	3877P102K
Cos	0490210F30	O PPM.	R10 and	3R77P274K

5496219P247

5494481P111

C68 5494481P111

C69 5496219P249

SCRIPTION		SAMBOL	GE PART NU.
f ±5%, 500 VDCW, temp coef	ľ	C73	5496267P18
pf ±20%, 1000 VDCW; sim to		C74	19A115414P13
pf ±5%, 500 VDCW, temp coef	-	C75	5494481P107
	١	C76	5493366P470K
pf ±5%, 500 VDCW, temp coef		C77	5493366P270K
pf ±5%, 500 VDCW, temp coef			
of ±10%, 500 VDCW, temp coef	Ì		
pf ±10%, 1000 VDCW; sim to		CR1 and CR2	19A115250P1
pf ±10%, 500 VDCW, temp coef		CR3 thru	19A115603P1
pf ±10%, 500 VDCW, temp coef		CR6 CV1	5495769P8
of ±10%, 100 VDCW; sim to		and CV2	
of ±5%, 100 VDCW; sim to	١	<b>J</b> 1	4033513P4
pf ±10%, 500 VDCW, temp coef		thru J17	
pf ±10%, 500 VDCW, temp coef			10000450650
of ±5%, 500 VDCW, temp coef	П	L1 L2	19B204526G2 19B204526G1
		L3	19B204526G4
O pf ±20%, 1000 VDCW; sim to	П	R1 L4	3R152P333J 19B204526G3
0 pf ±20%, 1000 VDCW; sim to	ı	R1	3R152P333J
pf ±5%, 500 VDCW, temp coef		L5	7488079P48
of ±5%, 500 VDCW, temp coef	П		
pf ±5%, 500 VDCW, temp coef		Q1 and Q2	19A115123P1
pf ±5%, 500 VDCW, temp coef		Q3 thru Q5	19A115330P1
0 pf ±20%, 1000 VDCW; sim to		Q6 and Q7	19A115328P1
f ±0.25 pf, 500 VDCW, temp		Q8	19A115329P2
pf ±5%, 500 VDCW, temp coef			
±10%, 500 VDCW.		Rl	3R77P334K
pf ±10%, 100 VDCW; sim to e DM-15.	١	R2	3R77P105K
pf ±0.25 pf 500 VDCW, temp coef		R3	3R77P472K
		R4	3R77P224K
pf ±5%, 500 VDCW, temp coef	l	R5	3R77P334K 3R77P684K
pf ±5%, 500 VDCW, temp coef	١	R6 R7	3R77P334K
0 pf ±10%, 1000 VDCW; sim to	l	R8	3R77P823K
o pr 110%, 1000 vice, srm to	l	R9	3R77P102K
f ±0.25 pf, 500 VDCW, temp coef	١	R10 and	3R77P274K
0 pf ±20%, 1000 VDCW; sim to	l	R11 R12*	19B209358P10
pf ±5%, 500 VDCW, temp coef			132233335710
00 pf $\pm 20\%$ , 1000 VDCW; sim to			19B201969P6
pf ±5%, 500 VDCW, temp coef		R13	3R77P224K
00 pf ±20%, 1000 VDCW; sim to		and R14	
		R15	3R77P333K
	1	1	1

			_		
DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.
Tantalum: 6.8 µf ±20%, 35 VDCW; sim to Sprague	R16	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	Т5	19B204537G1
Type 150D.	R17	3R77P823K	Composition: 82,000 ohms ±10%, 1/2 w.		
Polyester: 0.1 µf ±20%, 200 VDCW.	R18	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	XY1	
Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.	R19	3R77P222K	Composition: 2200 ohms ±10%, 1/2 w.	thru XY4	
Silver mica: 470 pf ±10%, 100 VDCW; sim to Electro Motive Type DM-15.	R20	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.		
Silver mica: 270 pf ±10%, 100 VDCW; sim to	R21	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.		
Electro Motive Type DM-15.	R 22	3R77P682K 3R77P153K	Composition: 6800 ohms ±10%, 1/2 w.		
DIODES AND RECTIFIERS	R23 R24	3R77P153K 3R77P682K	Composition: 15,000 ohms $\pm 10\%$ , $1/2$ w.  Composition: 6800 ohms $\pm 10\%$ , $1/2$ w.	Y1	19B206175P6
Silicon.	R25	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	thru Y4	
	R26	3R77P682K	Composition: 6800 ohms ±10%, 1/2 w.	Y1 thru	19B206175P7
Silicon.	R27	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	¥4	
	and R28				
Varactor, silicon: 33 pf ±20% at 4 VDC; sim to Pacific Semiconductors Varicap Type V-595.	R29	3R77P272K	Composition: 2700 ohms ±10%, 1/2 w.		
	R30	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.		
JACKS AND RECEPTACLES	R31	3R77P152K	Composition: 1500 ohms ±10%, 1/2 w.	C101	5494481P12
Contact, electrical: sim to Bead Chain L93-3.	R32 and R33	3R77P103K	Composition: 10,000 ohms $\pm$ 10%, 1/2 w.	C104	5491271P6
INDUCTORS	R34*	19B209358P107	Variable, carbon film: approx 75 to 25,000 ohms ±10%, 0,25 w; sim to CTS Type X-201.	C105	5494481P12
Coil. Includes tuning slug 5491798P2.  Coil. Includes tuning slug 5491798P2.			In Exciter 19D402308Gl thru G6 earlier than	C106	19B209204P1
Coil. Includes tuning slug 5491798P2. Composition: 33,000 ohms ±5%, 1/4 w.		19B201969P7	REV D; 19D402308G7 thru G12 earlier than REV E: Variable, carbon film: .025 megohm ±20%, 0.1 w;	C107	7489162P7
Coil. Includes tuning slug 5491798P2. Composition: 33,000 ohms ±5%, 1/4 w.	R35	3R77P683K	sim to Centralab Series 4.  Composition: 68,000 ohms ±10%, 1/2 w.	C108	7489162P4
Choke, RF: 27 µh ±10%, 1.4 ohms DC res max; sim	R36	3E77P392K	Composition: 3900 ohms ±10%, 1/2 w.		
to Jeffers 4422-9K.	R37	3R77P750J	Composition: 75 ohms ±5%, 1/2 w.	C109	7489162P27
TRANSISTORS	R38	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	C110	7489162 <b>P</b> 31
Silicon, NPN; sim to Type 2N2712.	R39	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.	C111	19B209204P1
	R40	3R77P181K	Composition: 180 ohms ±10%, 1/2 w.		19820920471
Silicon, NPN.	R41	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.	C113	5493392P7
	R42 R43	3R77P270K 3R77P200J	Composition: 27 ohms $\pm 10\%$ , $1/2$ w. Composition: 20 ohms $\pm 5\%$ , $1/2$ w.	C115	19B209372P1
Silicon, NPN.	R44	3R77P223K	Composition: 22,000 ohms ±10%, 1/2 w.		5.400000P5
Silicon, NPN.	R45	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	C116	5493392P7
·	R46	19A116278P474	Metal film: 0.576 megohm ±2%, 1/2 w.	C118	7489162P8
RESISTORS	R47	3R77P391K	Composition: 390 ohms ±10%, 1/2 w.	C119*	7489162P7
Composition: 0.33 megohm ±10%, 1/2 w.	R48	3R77P470K	Composition: 47 ohms ±10%, 1/2 w.		
Composition: 1 megohm ±10%, 1/2 w.  Composition: 4700 ohms ±10%, 1/2 w.	R50	3R77P101K	Composition: 100 ohms ±10%, 1/2 w.		7489162P6
Composition: 0.22 megohm ±10%, 1/2 w.	R53	3R152P472K	Composition: 4700 ohms ±10%, 1/4 w.	11	748910220
Composition: 0.33 megohm ±10%, 1/2 w.				C121 and	
Composition: 0.68 megohm ±10%, 1/2 w.	RT1	19B209284P6	Disc: 75 ohms, color code blue.	C122	
Composition: 0.33 megohm ±10%, 1/2 w.	RT3	19B209284P2	Rod: 2140 ohms, color code red.	C125	7489162P2
Composition: 82,000 ohms $\pm 10\%$ , $1/2$ w.	RT5	19B209284P6	Disc: 75 ohms, color code blue.	C126	7489162P1
Composition: 1000 ohms $\pm 10\%$ , $1/2$ w.	RT7	19B209284P2	Rod: 2140 ohms, color code red.	C127	5494481P12
Composition: 0.27 megohm ±10%, 1/2 w.	RT9	19B209284P6	Disc: 75 ohms, color code blue.	(12)	0494401712
Wandahi.	RT11	19B209284P2 19B209284P6	Rod: 2140 ohms, color code red.  Disc: 75 ohms, color code blue.	C128	5493392P7
Variable, carbon film: approx 75 to 10,000 ohms ±10%, 0.25 w; sim to CTS Type X-201.	RT15	19B209284P2	Rod: 2140 ohms, color code red.	C130	5490272P17
In Exciter 19D402308Gl thru G6 earlier than REV D; 19D402308G7 thru G12 earlier than REV E:				C132	5493392P7
Variable, carbon film: .01 megohm $\pm 20\%$ , 0.1 w; sim to Centralab Series 4.	Tl	19B204534G1	Coil. Includes tuning slug 5491798P4.	C135*	19B209369P1
Composition: 0.22 megohm $\pm 10\%$ , $1/2$ w.	Т2	19B204531G1	Coil. Includes tuning slug 5491798P4.	11	7400160707
	Т3	19B204535G1	Coil. Includes tuning slug 5491798P4.	C136	7489162P27
Composition: 33,000 ohms ±10%, 1/2 w.	T4	19B204535G2	Coil. Includes tuning slug 5491798P4.	C138	7489162P27
				C140	7489162P27

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
Coil. Includes tuning slug 5491798P4.	C142	7485975P17	Ceramic, feed-thru: 470 pf ±20%, 750 VDCW; sim to Erie Style 327.
SOCKETS	C143		Refer to Mechanical Parts (RC-1465 items 14, 15
Refer to Mechanical Parts (RC-1465, items 1-4).	C144		Refer to Mechanical Parts (RC-1465 items 25, 26 35).
	C145		Refer to Mechanical Parts (RC-1465 items 16-20)
hen reordering give GE Part Number and specify xact frequency needed.	C147	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.
rystal frequency = (OF ÷ 36).	C148 and C149	5494481P12	Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.
uartz: freq range 11,000 to 12,566 KHz, temp ange -30°C to +85°C. (406-420 MHz Transmitter).	C150 thru C156	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FASC.
uartz: freq range 12,500 to 14,500 KHz, temp ange -30°C to +85°C. (450-470 MHz Transmitter).	C157	19B209282P1	Ceramic, feed-thru: 680 pf ±20%, 1000 VDCW; si to Sprague Type 544C.
CHASSIS AND PA ASSEMBLY 19E500865G1, G2	C158 and C159	5493392P7	Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.
CAPACITORS	C160*	19B209369P2	Mica: 2500 pf ±20%, 300 VDCW; sim to EF Johnso Type 124-113-18. Added to 19E500865G2 by REV B
eramic disc: 1000 pf ±10%, 1000 VDCW; sim to MC Type JF Discap.			DIODES AND RECTIFIERS
riable: approx 2.1-12.7 pf, 750 v peak; sim	CR101	4037822P1	Silicon.
eramic disc: 1000 pf ±10%, 1000 VDCW; sim to	CV101*	19A115809P2	Silicon, capacitive.
MC Type JF Discap. eramic disc: 220 pf ±10%, 500 VDCW, temp coef			In 19E500865Gl of REV A and earlier: In 19E500865G2 of REV C and earlier:
4700 PPM.		19A115809Pl	Silicon, capacitive.
lectro Motive Type DM-15.			
ilver mica: 8 pf ±0.5 pf, 500 VDCW; sim to lectro Motive Type DM-15.	El	19B200535P3	Feed-thru: sim to Sealectro ST-1500SL-C3.
ilver mica: 100 pf ±5%, 500 VDCW; sim to	E2	4029309P1	Feed-thru: sim to Sealectro FT-SM-27.
lectro Motive Type DM-15.	E3	4036032P5	Feed-thru: sim to Sealectro FT-SM-10.
ilver mica: 150 pf ±5%, 500 VDCW; sim to lectro Motive Type DM-15.	E7	4034512P2	Feed-thru: sim to Sealectro FT-SM-22-TUR.
cramic disc: 220 pf ±10%, 500 VDCW, temp coef			
Ceramic, feed-thru: 1000 pf +100% -0%, 500			BANDPASS FILTER
/DCW; sim to Allen-Bradley Type FA5C. /ariable: approx 2.3 to 24.3 pf; sim to EF Johnson Type V 193-0008-010.			NOTE: The bandpass filters are factory tuned.  If a filter component (except as shown below) is found to be defective, it is
beramic, feed-thru: 1000 pf +100% -0%, 500 DCW; sim to Allen-Bradley Type FA5C.			recommended that the entire filter assembly be replaced to maintain rated power output and spurious attenuation.
ilver mica: 15 pf ±5%, 500 VDCW; sim to lectro Motive Type DM-15.	FL101 FL102	19C303559G1 19C303559G2	405-420 KHz, 450-470 MHz,
ilver mica: 12 pf ±5%, 500 VDCW; sim to lectro Motive Type DM-15.	G101		LOW PASS FILTER ASSEMBLY
n REV B and earlier:			19C311802G1
ilver mica: 10 pf $\pm 0.5$ pf, $500$ VDCW; sim to lectro Motive Type DM-15.			
efer to Mechanical Parts (RC-1465 items 19, 31, 3,34).	C1	19A116080P103	Polyester: 0.022 µf ±10%, 50 VDCW.
	C2	19A116080P3	Polyester: 0.022 μf ±20%, 50 VDCW.
ilver mica: 6 pf ±0.5 pf, 500 VDCW; sim to lectro Motive Type DM-15.	СЗ	5494481P107	Ceramic disc: 470 pf $\pm 20\%,\ 1000$ VDCW; sim to RMC Type JF Discap.
Gilver mica: 5 pf ±0.5 pf, 500 VDCW; sim to	C4	19A116080P9	Polyester: 0.22 µf ±20%, 50 VDCW.

Polyester: 0.33 µf ±20%, 250 VDCW.

Silicon, NPN; sim to Type 2N2712.

Silicon, NPN; sim to Type 2N2712.

Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to RMC Type JF Discap.

---- JACKS AND RECEPTACLES ----

Contact, electrical; sim to Bead Chain L93-3.

- - - - - - - TRANSISTORS - - - - - -

19A116080P8

5494481P107

19B209243P14

5494481P111

4033513P4

19A115123Pl

19A115123P1

19A116080P3

Silver mica: 5 pf ±0.5 pf, 500 VDCW; sim to Electro Motive Type DM-15.

Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FASC.

Variable: 2 to 7.83 pf, 1250 v peak; sim to Johnson Type M.

Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.

Silver mica: 100 pf ±5%, 500 VDCW; sim to Electro Motive Type DM-15.

DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	G
Ceramic, feed-thru: 470 pf ±20%, 750 VDCW; sim			RESISTORS	P109 thru	402
to Erie Style 327.	R1	3R77P333K	Composition: 33,000 ohms ±10%, 1/2 w.	P113	
Refer to Mechanical Parts (RC-1465 items 14, 15).  Refer to Mechanical Parts (RC-1465 items 25, 26,	R2	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.	P114	402
35).	R3	3R77P274K	Composition: 0.27 megohm ±10%, 1/2 w.	Pll5 thru	402
Refer to Mechanical Parts (RC-1465 items 16-20).	R4	3R77P620J	Composition: 62 ohms ±5%, 1/2 w.	P117	
Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.	R5	3R77P822K	Composition: 8200 ohms ±10%, 1/2 w.		ł
Ceramic disc: 1000 pf ±10%, 1000 VDCW; sim to	R6	3R77P153K	Composition: 15,000 ohms ±10%, 1/2 w.	R101	19A
RMC Type JF Discap.	R7	3R77P102K	Composition: 1000 ohms ±10%, 1/2 w.	R102	19A
Ceramic, feed-thru: 1000 pf +100% -0%, 500	R8	3R77P183K	Composition: 18,000 ohms ±10%, 1/2 w.	R103	3R7
VDCW; sim to Allen-Bradley Type FA5C.	R9	3R77P184K	Composition: 0.18 megohm ±10%, 1/2 w.	R103	549
Ceramic, feed-thru: 680 pf ±20%, 1000 VDCW; sim	R10	3R77P622J	Composition: 6200 ohms ±5%, 1/2 w.	K104	"
to Sprague Type 544C.	R11	3R77P330K	Composition: 33 ohms ±10%, 1/2 w.	R105	3R7
Ceramic, feed-thru: 1000 pf +100% -0%, 500 VDCW; sim to Allen-Bradley Type FA5C.	R24	3R77P103K	Composition: 10,000 ohms ±10%, 1/2 w.	R106	3R7
	R25	3R77P473K	Composition: $47,000$ ohms $\pm 10\%$ , $1/2$ w.	R107	19A
Mica: 2500 pf ±20%, 300 VDCW; sim to EF Johnson Type 124-113-18. Added to 19E500865G2 by REV B.	R26	3R77P103K	Composition: 10,000 ohms $\pm$ 10%, 1/2 w.	R108	3R7
	R27	3R77P512K	Composition: 5100 ohms $\pm 10\%$ , $1/2$ w.	R109	3R7
DIODES AND RECTIFIERS				R112	3R7
Silicon.	RT1	5490828P30	Rod: 0.33 megohm ±10% res, 1 w max; sim to	R113	3R7
Silicon, capacitive.			Globar Type 783H-3.	R114*	3R7
In 19E500865Gl of REV A and earlier: In 19E500865G2 of REV C and earlier:		Į.	JACKS AND RECEPTACLES		
Silicon, capacitive.	J101	19C303426G1	Connector: 20 pin contacts.		3R7
	J102	19B205689G1	Connector: 18 electrical contacts.	R115	3R7
Feed-thru: sim to Sealectro ST-1500SL-C3.				R117	3R1
Feed-thru: sim to Sealectro FT-SM-27.	L101	7488079P35	Choke, RF: 2.2 \( \text{\pm h} \) \( \pm \) ±10%, 0.5 \( \text{ohm DC res max} \);	R118	3R7
Feed-thru: sim to Sealectro FT-SM-10.	1 2101	1400013230	sim to Jeffers 4412-9K.	R120*	3R7
Feed-thru: sim to Sealectro FT-SM-22-TUR.	L102	19A122524G2	Coil.		
	L103	19A122524G1	Coil.	R123	3R7
	L105	7488079P33	Choke, RF: 1 $\mu$ h $\pm 10\%$ , 0.15 ohm DC res max; sim to Jeffers $4412-5$ K.	R123	191
BANDPASS FILTER	L107	19B205615P2	Coil.	"	13.
NOTE: The bandpass filters are factory tuned.  If a filter component (except as shown	L108	19B205615P1	Coil.	R125	3R1
below) is found to be defective, it is recommended that the entire filter	L110	19B205614P2	Coil.	R126	3R7
assembly be replaced to maintain rated power output and spurious attenuation.	L111	19B205614P5	Coil.	R129	3R7
405-420 KHz.	L112	19B205614P4	Coil.	R130	3R7
450-470 MHz.	L113	19B205614P3	Coil.		
LOW PASS FILTER ASSEMBLY	L115	4036032P5	Feed-thru: sim to Sealectro FT-SM-10.	S101	403
19C311802G1	L116		Part of can assembly 19B205625Gl. Not recommended as a replaceable item.		
	L117	7772834P7	Choke, RF: 0.2 $\mu h$ ±10%, .034 ohm ±15% DC res, 320 to 520 MHz freq range; sim to Ohmite Z-460.	11	
Polyester: 0.022 µf ±10%, 50 VDCW.	L119	1	(Part of Mechanical Assembly, items 12, 13, 22,	TB1	777
Polyester: 0.022 μf ±20%, 50 VDCW.	and L120		and 23).	TB6	777
Ceramic disc: 470 pf $\pm 20^{\circ}$ , 1000 VDCW; sim to RMC Type JF Discap.	L122	7772834 <b>P</b> 7	Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC res, 320 to 520 MHz freq range; sim to Ohmite Z-460.	TB9 TB10	741
Polyester: 0.22 μf ±20%, 50 VDCW.	L124	19A121390P1	Coil.		
Polyester: 0.15 μf ±20%, 50 VDCW.	L125	19B205616P1	Coil.	V101	
Polyester: .022 µf ±20%, 50 VDCW.	and L126	1		V101 V102	
Ceramic disc: 470 pf $\pm 20\%$ , 1000 VDCW; sim to RMC Type JF Discap.	L127	19B204658P3	Grid line.	V102 V103	
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DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION	SYMBOL	GE PART NO.	DESCRIPTION
RESISTORS	P109	4029840P2	Contact, electrical: sim to AMP 42827-2.			TUNED CIRCUITS
Composition: 33,000 ohms ±10%, 1/2 w.	thru P113			Z101 C1	19B204543G2 5496203P468	Coil. Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW,
Composition: 18,000 ohms ±10%, 1/2 w.	P114	4029840P1	Contact, electrical: sim to AMP 41854.		0100001110	temp coef -5600 PPM.
Composition: 0.27 megohm ±10%, 1/2 w.	Pl15 thru	4029840P2	Contact, electrical: sim to AMP 42827-2.	Z102 C1	19B204543G1 5496203P468	Coil. Includes tuning slug 5491798P4. Capacitor, ceramic disc: 510 pf ±5%, 500 VDCW,
Composition: 62 ohms ±5%, 1/2 w.	P117		2222222			temp coef -5600 PPM.
Composition: 8200 ohms ±10%, 1/2 w.	R101	19A115416P1				
Composition: 15,000 ohms ±10%, 1/2 w.	l kioi	19411041071	to Dale Type RS-2B.			HARNESS ASSEMBLY 19E500865G5
Composition: 1000 ohms ±10%, 1/2 w.	R102	19A115416P3	Precision, wirewound: 2.59 ohms ±1%, 2 w; sim to Dale Type RS-2B.			(Includes J101, J102, P101-P106, P109-P111, P115-P117, R103, R104)
Composition: 18,000 ohms ±10%, 1/2 w.  Composition: 0.18 megohm ±10%, 1/2 w.	R103	3R77P330J	Composition: 33 ohms ±5%, 1/2 w.		İ	
Composition: 6200 ohms ±5%, 1/2 w.	R104	5493035P11	Wirewound: 40 ohms ±5%, 5 w; sim to Hamilton			MECHANICAL PARTS
Composition: 33 ohms ±10%, 1/2 w.	R105	3R77P393J	Hall Type HR.  Composition: 39,000 ohms ±5%, 1/2 w.			(SEE RC-1465)
Composition: 10,000 ohms ±10%, 1/2 w.	R106	3R77P431J	Composition: 430 ohms ±5%, 1/2 w.	1	19B200525P9	Rivet. (Part of XY1-4 in Al01-112).
Composition: 47,000 ohms ±10%, 1/2 w.	R107	19A116278P444	Metal film: 0.28 megohm ±2%, 1/2 w.	2	19A115793P1	Contact, electrical: sim to Malco 2700. (Part of XY1-4 in Al01-112).
Composition: 10,000 ohms ±10%, 1/2 w.	R108	3R77P683J	Composition: 68,000 ohms ±5%, 1/2 w.	3	19C311172P2	Socket. (Part of XY1-4 in A101-112).
Composition: 5100 ohms ±10%, 1/2 w.	R109	3R79P273K	Composition: 27,000 ohms ±10%, 2 w.	4	4033089P1	Clip. (Part of XY1-4 in Al01-112).
	R112	3R77P103J	Composition: 10,000 ohms ±5%, 1/2 w.	5	19C311152P1	Heat sink.
Rod: 0.33 megohm ±10% res, 1 w max; sim to	R113	3R77P104J	Composition: 0.1 megohm ±5%, 1/2 w.	6	7165167P5	Insert, tube shield: sim to Atlas Insert 106-332-5. (Used with V101).
Globar Type 783H-3.	R114*	3R77P201J	Composition: 200 ohms ±5%, 1/2 w.	7	19B204570P3	Heat sink. (Used with V101).
			In 19E500865Gl of REV A and earlier: In 19E500865G2 of REV C and earlier:	8	19A122497P1	Support. (Used with V101).
Connector: 20 pin contacts.		3R77P681J	Composition: 680 ohms ±5%, 1/2 w.	9	7165167P9	Insert, tube shield: sim to Atlas Insert
Connector: 18 electrical contacts.	R115	3R77P510J	Composition: 51 ohms ±5%, 1/2 w.			106-332-21. (Used with V102).
	R117	3R149P223J	Composition: 22,000 ohms ±5%, 4 w.	10	19A122497P2 19A122498P1	Support. (Used with V102).  Heat sink. (Used with V102).
Choke, RF: 2.2 µh ±10%, 0.5 ohm DC res max;	R118	3R78P473K	Composition: 47,000 ohms ±10%, 1 w.	12	19C311164P4	Plate line. (Used with L120).
sim tó Jeffers 4412-9K.	R120*	3R77P472J	Composition: 4700 ohms ±5%, 1/2 w.	13	19C311164P5	Plate line. (Used with L119).
Coil.	1		In 19E500865Gl of REV A and earlier: In 19E500865G2 of REV C and earlier:	14	19C311166P2	Base line. (Mounts L119, 120, Part of C143).
Coil.  Choke, RF: 1 µh ±10%, 0.15 ohm DC res max;	R123	3R77P152K	Composition: 1500 ohms ±10%, 1/2 w.	15	19A121350Pl	Insulator. (Part of C143).
sim to Jeffers 4412-5K.	R124	19B209381P1	Variable, composition: 10,000 ohms ±20%, 3 w; sim to Allen-Bradley Type K.	16	19A122526G1	Support. (Part of Cl45).
Coil.	R125	3R149P153K	Composition: 15,000 ohms ±10%, 4 w.	17	19A122516P1	Slide. (Part of Cl45).
Coil.	R126	3R79P562K	Composition: 5600 ohms ±10%, 2 w.	18	19A122709P1	Set screw. 6-32. (Part of Cl45),
Coil.	R129	3R78P391J	Composition: 390 ohms ±5%, 1 w.	19	7137968P8	Nut, stamped: thd size No. 6-32; sim to Palnut TO632005. (Part of Cl21, Cl22, Cl45).
Coil.	R130	3R77P683K	Composition: 68,000 ohms ±10%, 1/2 w.	20	19A122518G1	Spring. (Part of Cl45).
Coil.				21	19C303544P2	Cover. (Used with V103).
Feed-thru: sim to Sealectro FT-SM-10.	S101	4031922P1	Pushbutton: SPST, normally open, 1/2 amp at	22	19D402783P5	Plate line. (Used with L120).
Part of can assembly 19B205625Gl. Not recom-	1	10010111	12 VDC; sim to Stackpole Type SS-15.	23	19C311164P6	Plate line. (Used with L119).
mended as a replaceable item.  Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC res,				24	19C303405P2	Casting. (Part of Cl21, Cl22).
320 to 520 MHz freq range; sim to Ohmite Z-460.	TBl	7775500 <b>P</b> 9	Phen: 5 terminals.	25	4031593P1	Washer. (Part of C144).
(Part of Mechanical Assembly, items 12, 13, 22, and 23).	TB6	7775500P10	Phen: 4 terminals.	26 27	4032084P1 19B204395G2	Washer, insulated. (Part of C144). Chassis.
	тв9	7487424Pl	Miniature, phen: 1 terminal.	28*	19B204393G2	Heat sink. (Used with Q8 in A101-A112).
Choke, RF: 0.2 µh ±10%, .034 ohm ±15% DC res, 320 to 520 MHz freq range; sim to Ohmite Z-460.	TBlO	7487424P2	Miniature, phen: 1 terminal.	26*	19820433371	(Deleted from Exciter 19D402308Gl thru G6 by REV E, 19D402308G7 thru G12 by REV F.
Coil.	V101			29*	19B204394P1	Support. (Used with Q8 in AlOl-All2). Deleted from Exciter 19D402308G1 thru G6 by REV E, 19D402308G7 thru G12 by REV F.
	V102		Type 8156.	30	19C303495G8	Station Top Cover. (Except Repeaters and VM).
Grid line.	V103		Туре 8072.		19C303673G3	Station Top Cover. (Repeaters and VM only).
Grid line.	1		SOCKETS		19C303396G1	Mobile Top Cover.
PLUGS	XV101	7480532P8	Tube, phen: 9 pins; sim to Elco 04-903-84.	31	4036765G4	Set Screw. (Part of C121, C122).
Contact, electrical: sim to AMP 42827-2.	XV101 XV102	19C301007P5	Tube, plastic: 12 pins; sim to Alcon Metal	32	19A121676P1	Guide pin: 4-40 thread, (Used with J101).
Contact, electrical: sim to AMP 41854.			Products 371G.	33	4036899P4	Insulator, standoff: sim to Centralab 3BX3778C. (Part of C121, C122).
Contact, electrical: sim to AMP 42827-2.	XV103	19B209160P1	Tube, plastic: 11 pins; sim to EF Johnson 124-311-100.	34	4036765G2	Screw. (Part of C121, C122).
		1		35	4031594P1	Insulator. (Part of C144).
		1				
				l 1	1	

SYMBOL	GE PART NO.	DESCRIPTION
36 37 38 39 40 41 42 43*	GE PART NO.  4036921P1 198204366P1 4038930P1 4029030P10 19C303495G7 19C303396G3 19A121065P1 19A127257G1 4036555P1	Bracket, angle: sim to Tinnerman C17609-8A-67. Support. Clip. (Mounts R104). Rubber Channel. Station Bottom Cover. Mobile Bottom Cover. (Not Used). (Not Used). Insulator, disc: nylon. (Added to Exciter 19D402308G7 thru G6 by REV E, 19D402308G7 thru G12 by REV F.

### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

### CHANNEL GUARD LOW PASS FILTER G101

Rev. A & B - Incorporated into initial shipment

### EXCITER BOARD A101-A112 (19D412308G1 thru G12)

Rev. A thru C - 19D402308G1 thru G6 Rev. A thru D - 19D402308G7 thru G12

Incorporated into initial shipments.

19D402308G1 thru G6 19D402308G7 thru G12 Rev. D -

To improve stability and facilitate adjustment of modulation limiting and Channel Guard levels. Changed R12 and R34.

19D402308G1 thru G6 19D402308G7 thru G12 Rev. E -Rev. F -

To facilitate manufacturing. Deleted the heat sink and mechanical parts to mount Q8. Added parts to mount Q8 on the board.

#### CHASSIS & PA ASSEMBLY

19E500865G1 & G2

To improve assembly. Changed items 12,13,14,22 and 23 of mechanical Parts List.

Rev. B -19E500865G2

To increase grid drive. Deleted C135 and added C160 for high splits.

Rev. C -

To increase grid drive. Changed Cl19

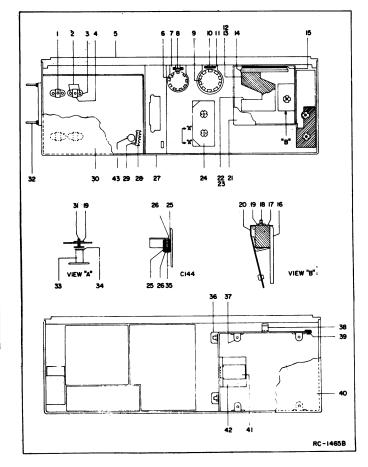
Rev. D -To incorporate a new diode. Changed CV101. Replaced R120 with R133, and R114 with R134.

19E500865G1

To incorporate new diode. Changed CV101. Replaced R120 with R133 and R114 with R134.

Rec. C -19E500865G1

To increase grid drive. Delete C135. Add C160.



4ET59DIO-41 4ET60DIO-41

### PARTS LIST

LBI-3936D

CHANNEL GUARD ENCODER G102 4EH17A10 19C311802-G2

SYMBOL	GE PART NO.	DESCRIPTION
C1+	19B209243-P103	Polyester: 0.022 $\mu f$ ±10%, 50 VDCW. Earlier than REV A:
	19B209243-P2	Polyester: 0.015 µf ±20%, 50 VDCW.
C2	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
СЗ	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C4	19B209243-P9	Polyester: 0.22 µf ±20%, 50 VDCW.
C5	19B209243-P8	Polyester: 0.15 µf ±20%, 50 VDCW.
C6	19B209243-P3	Polyester: 0.022 µf ±20%, 50 VDCW.
C7	5494481-P107	Ceramic disc: 470 pf ±20%, 1000 VDCW; sim to RMC Type JF Discap.
C8	19B209243-P14	Polyester: 0.33 µf ±20%, 250 VDCW.
C9	5496267-P1	Tantalum: 6.8 $\mu$ f $\pm$ 20%, 6 VDCW; sim to Sprague Type 150D.
C10	19B209243-P117	Polyester: 0.22 µf ±10%, 50 VDCW.
Cll thru Cl3	5494481-P111	Ceramic disc: .001 $\mu f$ ±20%, 1000 VDCW; sim to RMC Type JF Discap.
		DIODES AND RECTIFIERS
CR1 and CR2	19A115250-P1	Silicon.
PL1		TONE FREQUENCY NETWORK 19B205280
	198205280-G2 198205280-G2 198205280-G2 198205280-G3 198205280-G6 198205280-G6 198205280-G6 198205280-G6 198205280-G9 198205280-G1 198205280-G2 198205280-G2 198205280-G2	71.9 Hz 77.0 Hz 82.5 Hz 88.5 Hz 94.8 Hz 100.0 Hz 103.5 Hz 110.9 Hz 110.9 Hz 110.9 Hz 110.9 Hz 110.9 Hz 111.8 Hz 123.0 Hz 127.3 Hz 131.8 Hz 131.8 Hz 131.8 Hz 141.3 Hz 141.3 Hz 141.3 Hz 151.4 Hz 151.4 Hz 152.2 Hz 151.4 Hz 162.2 Hz 151.4 Hz 162.2 Hz 179.8 Hz 179.8 Hz 179.8 Hz
J1	4033513-P4	JACKS AND RECEPTACLES
thru J6		Contact, electrical; sim to Bead Chain L93-3.
Q1 and Q2	19A115123-P1	Silicon, NPN; sim to Type 2N2712.
Q3 thru Q5	19A115362-P1	Silicon, NPN; sim to Type 2N2925.
R1	3R77-P333K	Composition: 33,000 ohms ±10%, 1/2 w.
R2	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.

*COMPONENTS ADDED, D	ELETED OR	CHANGED BY	PRODUCTION	CHANGES

SYMBOL	GE PART NO.	DESCRIPTION
R3	3R77-P274K	Composition: 0.27 megohms ±10%, 1/2 w.
R4	3R77-P620J	Composition: 62 ohms ±5%, 1/2 w.
R5	3R77-P822K	Composition: 8200 ohms ±10%, 1/2 w.
R6	3R77-P153K	Composition: 15,000 ohms ±10%, 1/2 w.
R7	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
R8	3R77-P183K	Composition: 18,000 ohms ±10%, 1/2 w.
R9	3R77-P184K	Composition: 0.18 megohms ±10%, 1/2 w.
R10	3R77-P622J	Composition: 6200 ohms ±5%, 1/2 w.
R11	3R77-P330K	Composition: 33 ohms ±10%, 1/2 w.
R12	5495948-P365	Deposited carbon: 46,400 ohms ±1%, 1/2 w; sim to Texas Instrument CD1/2MR.
R13	3R77-P682J	Composition: 6800 ohms ±5%, 1/2 w.
R14	3R77-P244J	Composition: 0.24 megohms ±5%, 1/2 w.
R15	19A116278-P233	Metal film: 2150 ohms ±2%, 1/2 w.
R16	19A116278-P301	Metal film: 10,000 ohms $\pm 2\%$ , 1/2 w.
R17	19A116278-P65	Metal film: 46.4 ohms $\pm 2\%$ , $1/2$ w.
R18	19A116278-P329	Metal film: 19,600 ohms ±2%, 1/2 w.
R19	19A116278-P285	Metal film: 7500 ohms ±2%, 1/2 w.
R20	19A116278-P412	Metal film: 130,000 ohms ±2%, 1/2 w.
R21	19A116278-P269	Metal film: 5110 ohms $\pm 2\%$ , $1/2$ w.
R22	19A116278-P117	Metal film: 147 ohms ±2%, 1/2 w.
R23	3R77-P102K	Composition: 1000 ohms ±10%, 1/2 w.
RT1	5490828-P30	Thermistor: 330,000 ohms $\pm$ 10%, color code black and gray; sim to Globar Type 783H-3.
RT2	5490828-P36	Thermistor: $55,000$ ohms $\pm 10\%$ , color code black and red; sim to Globar Type 723B.
Wl		(Part of XFL1).
XFL1	19A121920-G3	Reed, mica-filled phen: 7 pins rated at 1 amp at 500 VRMS with 4-1/4 inches of cable.
		ENCODER INSTALLATION KIT 19A127174-G1
		MISCELLANEOUS
	N404P13C13	Lockwasher, no. 6.
	N 80 P1 3005 C1 3	Machine screw, no. 6-32 x 5/16.
	19B201074-P304	Tap screw, no. 6-32 x 1/4.
	N210P13C13	Nut, no. 6-32.
	19B205480-G2	Harness. Includes:
P130 thru P135	4029840-P2	Contact, electrical; sim to Amp 42827-2.

### **PRODUCTION CHANGES**

Changes in the equipment to improve performance or to simplify circuits are identified by a "Revision Letter", which is stamped after the model number of the unit. The revision stamped on the unit includes all previous revisions. Refer to the Parts List for descriptions of parts affected by these revisions.

REV. A - To improve Channel Guard low pass filter. Changed Cl.

### **ORDERING SERVICE PARTS**

Each component appearing on the schematic diagram is identified by a symbol number, to simplify locating it in the parts list. Each component is listed by symbol number, followed by its description and GE Part Number.

Service parts may be obtained from Authorized GE Communication Equipment Service Stations or through any GE Radio Communication Equipment Sales Office. When ordering a part, be sure to give:

- 1. GE Part Number for component

- Description of part
   Model number of equipment
   Revision letter stamped on unit

These instructions do not purport to cover all details or variations in equipment nor to provide for every possible contingency to be met in connection with installation, operation or maintenance.

Should further information be desired, or should particular problems arise which are not covered sufficiently for the purchaser's purposes, contact the nearest Radio Communication Equipment Sales Office of the General Electric Company.

LBI-3998

DF-3126

MOBILE RADIO DEPARTMENT
GENERAL ELECTRIC COMPANY ● LYNCHBURG, VIRGINIA 24502

